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DATE MAILED: 07/31/2002

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION 10.
09/904,360	07/12/2001	Giuseppe Curello	Z&PINFP-08190 1413	
LERNER AND GREENBERG, P.A. Post Office Box 2480 Hollywood, FL 33022-2480			EXAMINER	
			ANYA, IGWE U	
			ART UNIT	PAPER NUMBER
			2825	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)				
		09/904,360	CURELLO ET AL.				
-,	Office Action Summary	Examiner	Art Unit				
		Igwe U. Anya	2825				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address							
Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status							
1)⊠	Responsive to communication(s) filed on 12.	July 2001 .					
2a)□	This action is FINAL . 2b)⊠ Th	nis action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. Disposition of Claims							
	Claim(s) <u>1-20</u> is/are pending in the application	1					
1	4a) Of the above claim(s) is/are withdra						
5) Claim(s) is/are allowed.							
6)🖂	Claim(s) 1-11 is/are rejected.						
7)⊠ Claim(s) <u>12-20</u> is/are objected to.							
8) Claim(s) are subject to restriction and/or election requirement.							
Application Papers							
9)☐ The specification is objected to by the Examiner.							
10)⊠ The drawing(s) filed on <u>12 July 2001</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.							
If approved, corrected drawings are required in reply to this Office action.							
12) The oath or declaration is objected to by the Examiner.							
Priority under 35 U.S.C. §§ 119 and 120							
13)⊠ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).							
a)⊠ All b)□ Some * c)□ None of:							
1.⊠ Certified copies of the priority documents have been received.							
	2. Certified copies of the priority document	ts have been received in Appli	cation No				
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.							
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).							
a) The translation of the foreign language provisional application has been received. 15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.							
Attachmen	t(s)						
2) Notic	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449) Paper No(s) 2	5) Notice of Infor	mary (PTO-413) Paper No(s) mal Patent Application (PTO-152) .				
U.S. Patent and 1 PTO-326 (Re		ction Summary	Part of Paper No. 7				

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DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in-
- (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effect under this subsection of a national application published under section 122(b) only if the international application designating the United States was published under Article 21(2)(a) of such treaty in the English language; or
- (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that a patent shall not be deemed filed in the United States for the purposes of this subsection based on the filing of an international application filed under the treaty defined in section 351(a).
- 2. Claims 1 to 3 and 8 to 11 are rejected under 35 U.S.C. 102(b) as being anticipated by Vasudev (US Patent Number 4617066).
- 3. Vasudev teaches a process of ion implanting a silicon substrate with silicon and germanium ions to form a polycrystalline (50)and amorphous (20) layers, and performing a two step anneal to produce an epitaxial layer (12) and a buried doping (64), including an RTA at 1000 1150 degrees C for 1 second. (figs. 1 & 2, and columns 5 9). Further, teaches a polysilicon of thickness 250 nanometers (column 5 line 29), amorphous silicon of thickness 200 nanometers (column 6 line 23), and the dopant species (column 7, see table).

Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

- 5. Claims 4 to 7 are rejected under 35 U.S.C. 103(a) as being unpatentable over Vasudev (US Patent Number 4617) in view of Maszara et al. (US Patent Number 6362063).
- 6. Vasudev teaches the feature previously outlined, but lacks: the amorphous layer having a thickness of 500 – 1000 nanometers; and performing an RTA of 1000 – 1100 degrees C for 10 to 60 seconds.
- 7. However, Maszara et al. teach these parameters to be adjustable and including the use of boron for implantation (columns 3 and 4); and further teach the formation of a Mosfet device after the low temperature anneal (column 6 lines 47 67, & figs. 1, 3)
- 8. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to incorporate the teachings of Maszara et al. into the Vasudev reference to adjust any of the parameters. Where the general conditions of a claim are disclosed in prior art, discovering the optimum or workable ranges involves only routine skill in the art. In re Aller, 105 USPQ 233.
- 9. Claims 12 to 20 are objected to as being dependent upon a rejected claim, but would be allowable if rewritten in independent form.
- 10. Prior art considered but not used in the rejections include Turner et al. (US Patent Number 6048781), Chiang et al. (US Patent Number 5008210), and Liu (US Patent Number 5393682).

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11. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Igwe U. Anya whose telephone number is (703) 308-3549. The examiner can normally be reached on M - F 8:30am - 5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew S. Smith can be reached on (703) 308-1323. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 872-9318 for regular communications and (703) 872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Igwe U. Anya Examiner Art Unit 2825

IA July 28, 2002

> MATTHEW SMITH SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800